

MUR420

Vishay General Semiconductor

Ultrafast Plastic Rectifier



4.0 A

200 V 150 A

25 ns

0.710 V

175 °C

PRIMARY CHARACTERISTICS

I_{F(AV)}

 V_{RRM}

I_{FSM}

t_{rr}

 V_{F}

T_J max.

FEATURES

- Glass passivated chip junction
- Ultrafast reverse recovery time
- Low forward voltage drop
- Low leakage current
- · Low switching losses, high efficiency
- High forward surge capability
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer and telecommunication.

MECHANICAL DATA

Case: DO-201AD

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

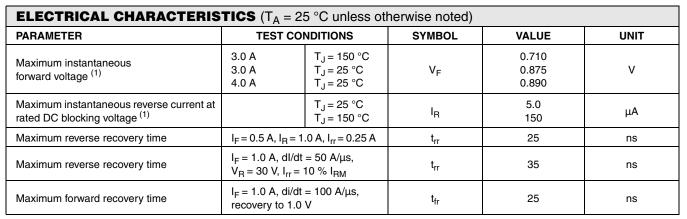
Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Maximum repetitive peak reverse voltage	V _{RRM}	200	V			
Working peak reverse voltage	V _{RWM}	200	V			
Maximum DC blocking voltage	V _{DC}	200	V			
Maximum average forward rectified current at T_{A} = 80 °C (Fig. 1)	I _{F(AV)}	4.0	А			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	SM 150				
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175	°C			





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Note:

(1) Pulse test: t_p = 300 µs, duty cycle \leq 2 %

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
SYMBOL	VALUE	UNIT			
$R_{ ext{ heta}JA}$	28	°C/W			
/	SYMBOL	SYMBOL VALUE			

Note:

(1) Lead length = 1/2" on P.C. board with 1/2" x 1/2" copper surface

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
MUR420-E3/54	1.138	54	1400	13" diameter paper tape and reel		
MUR420-E3/73	1.138	73	1000	Ammo pack packaging		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

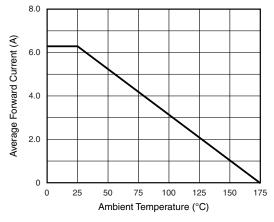


Figure 1. Forward Current Derating Curve

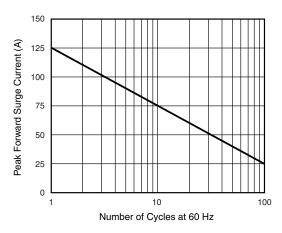


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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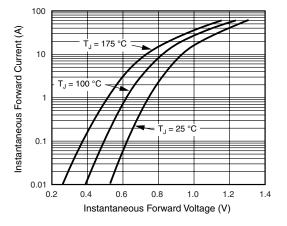


Figure 3. Typical Instantaneous Forward Characteristics

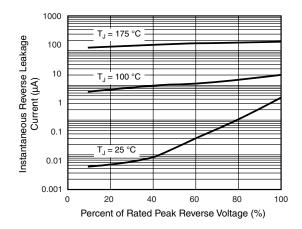
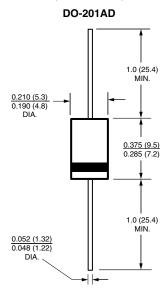


Figure 4. Typical Reverse Leakage Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



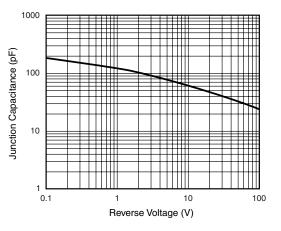


Figure 5. Typical Junction Capacitance



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